

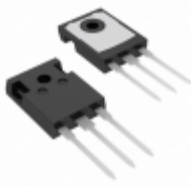


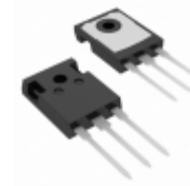

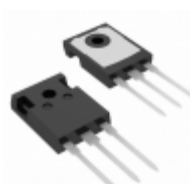

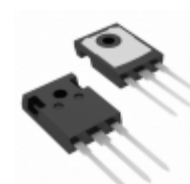
	<h2 style="color: red;">FGH40N6S2</h2> <p><b>Hersteller-Teilenummer:</b> <a href="#">FGH40N6S2</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> IGBT 600V 75A 290W TO247</p> <p><b>Datenblätter:</b>  <a href="#">FGH40N6S2.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 5640 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FGH40N6S2</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	IGBT 600V 75A 290W TO247
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-IGBTs-</a>
Teilstatus	5640 pcs Stock
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Leistung - max	290W
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Strom - Kollektor (Ic) (max)	75A
Spannung - Kollektor-Emitter-Durchbruch (max)	600V
IGBT-Typ	-
VCE (on) (Max) @ Vge, Ic	2.7V @ 15V, 20A
Strom - Collector Pulsed (Icm)	180A
Schaltenergie	115µJ (on), 195µJ (off)
Gate-Ladung	35nC
Td (ein / aus) bei 25 ° C	8ns/35ns
Testbedingung	390V, 20A, 3 Ohm, 15V
Verpackung	Tube

FGH40N6S2 ist neu im Original, Suche FGH40N6S2 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FGH40N6S2 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FGH40N6S2: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FGH40T100SMD</b> AMI Semiconductor / ON Semiconductor IGBT 1000V 80A 333W TO247-3</p>	 <p><b>FGH40N65UFDTU</b> AMI Semiconductor / ON Semiconductor IGBT 650V 80A 290W TO247</p>	 <p><b>FGH40N65UFDTU</b> Fairchild/ON Semiconductor IGBT 650V 80A 290W TO247</p>	 <p><b>FGH40N6S2D</b> AMI Semiconductor / ON Semiconductor IGBT 600V 75A 290W TO247</p>
 <p><b>FGH40N6S2D</b> Fairchild/ON Semiconductor IGBT 600V 75A 290W TO247</p>	 <p><b>FGH40N65UFDTU_F085</b> Fairchild/ON Semiconductor IGBT 650V 40A 290W TO247</p>	 <p><b>FGH40T100</b> Fairchild/ON Semiconductor FGH40T100 FAIRCHILD</p>	 <p><b>FGH40N65UFDTU-F085</b> AMI Semiconductor / ON Semiconductor IGBT 650V 40A 290W TO247</p>

### heiße Teile

Mehr

 FGH30N6S2	 FGH30N6S2D	 FGH30N6S2D	D FGH30S130P	 FGH30S130P
 FGH30T65UPDT	 FGH40N60SF	D FGH40N60SFD	 FGH40N60SFDTU	 FGH40N60SFDTU
 FGH40N60SFTU	 FGH40N60SFTU	 FGH40N60SMD	 FGH40N60SMD	 FGH40N60SMDF
D FGH40N60SMDF	 FGH40N60UF	 FGH40N60UFD	 FGH40N60UFDTU	 FGH40N60UFDTU
 FGH40N60UFTU	 FGH40N60UFTU	 FGH40N65UFD	 FGH40N65UFDTU	 FGH40N65UFDTU
 FGH40N6S2	 FGH40N6S2D	D FGH40N6S2D	 FGH40T100SMD	 FGH40T100SMD
 FGH40T120SMD	D FGH40T120SMD	 FGH40T65SHDF	 FGH40T65SPD	 FGH50N6S2
 FGH50N6S2	 FGH50N6S2D	 FGH50N6S2D	 FGH50T65SQD	 FGH50T65UPD
 FGH50T65UPD	 FGH60N60SF	 FGH60N60SFD	D FGH60N60SMD	 FGH60N60SMD
 FGH60N60UFD	 FGH60N6S2	 FGH60N6S2	 FGH60T65SHD	 FGH75N60SF

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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